



AF
IPW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:
Fu-Hsin Chen

Serial No.: 10/801,234

Filed: March 16, 2004

For: HIGH-VOLTAGE MOS TRANSISTOR
AND METHOD FOR FABRICATING
THE SAME

§
§
§
§
§
§
§
§
§

Attorney Docket No. 24061.79
(TSMC2003-0322)

Customer No. 42717

Group Art Unit: 2826

Examiner: Dickey, Thomas L.

RESPONSE AFTER FINAL OFFICE ACTION

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Final Office Action mailed September 28, 2005, please reconsider the application in light of the following remarks:

A Listing of the Claims begins on page 2 of this paper.

Remarks begin on page 5 of this paper.